



# Si4020 Universal ISM Band FSK Transmitter

## DESCRIPTION

Silicon Labs' Si4020 is a single chip, low power, multi-channel FSK transmitter designed for use in applications requiring FCC or ETSI conformance for unlicensed use in the 315, 433, 868, and 915 MHz bands. Used in conjunction with IA4320, Silicon Labs' FSK receiver, the Si4020 transmitter feature EZRadio™ technology, which produces a flexible, low cost, and highly integrated solution that does not require production alignments. All required RF functions are integrated. Only an external crystal and bypass filtering are needed for operation.

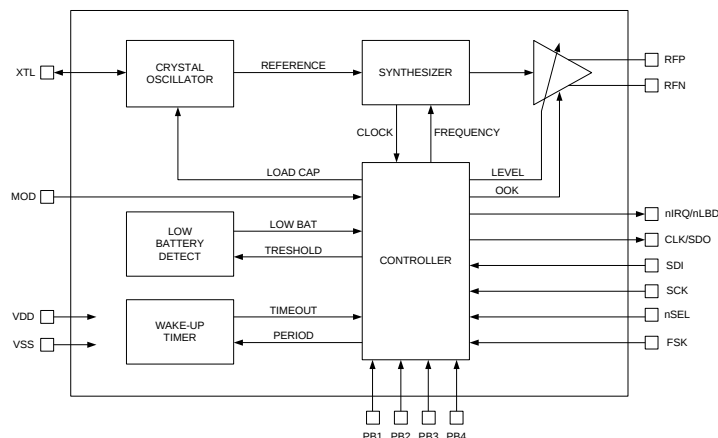
The Si4020 features a completely integrated PLL for easy RF design, and its rapid settling time allows for fast frequency hopping, bypassing multipath fading and interference to achieve robust wireless links. In addition, highly stable and accurate FSK modulation is accomplished by direct closed-loop modulation with bit rates up to 256 kbps. The PLL's high resolution allows the use of multiple channels in any of the bands.

The integrated power amplifier of the transmitter has an open-collector differential output that directly drive a loop antenna with programmable output level. No additional matching network is required. An automatic antenna tuning circuit is built in to avoid costly trimming procedures and de-tuning due to the "hand effect".

For low-power applications, the device supports automatic activation from sleep mode. Active mode can be initiated by several wake-up events (on-chip timer timeout, low supply voltage detection, or activation of any of the four push-button inputs).

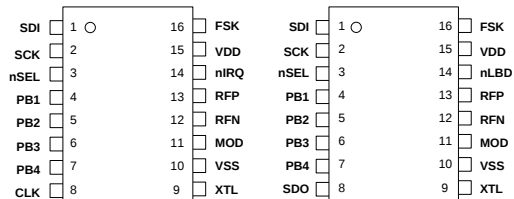
The Si4020's on-chip digital interface supports both a microcontroller mode and an EEPROM mode. The latter allows complete data transmitter operation without a microcontroller (both control commands and data are read from the EEPROM). Any wake-up event can start a transmission of the corresponding data stored in the EEPROM.

## FUNCTIONAL BLOCK DIAGRAM



## Si4020

### PIN ASSIGNMENT



Microcontroller Mode

EEPROM Mode

**This document refers to Si4020-IC Rev I1.**

See [www.silabs.com/integration](http://www.silabs.com/integration) for any applicable errata. See back page for ordering information.

## FEATURES

- Fully integrated (low BOM, easy design-in)
- No alignment required in production
- Fast settling, programmable, high-resolution PLL
- Fast frequency hopping capability
- Stable and accurate FSK modulation with programmable deviation
- High bit rate (up to 256 kbps)
- Direct loop antenna drive
- Automatic antenna tuning circuit
- Programmable output power level
- Alternative OOK support
- EEPROM mode supported
- SPI bus for applications with microcontroller
- Clock output for microcontroller
- Integrated programmable crystal load capacitor
- Power-saving sleep mode
- Multiple event handling options for wake-up activation
- Push-button event handling with switch de-bounce
- Wake-up timer
- Low battery detection
- 2.2 to 5.4 V supply voltage
- Low power consumption
- Low standby current (0.3  $\mu$ A)
- Compact 16-pin TSSOP package

## TYPICAL APPLICATIONS

- Remote control
- Home security and alarm
- Wireless keyboard/mouse and other PC peripherals
- Toy control
- Remote keyless entry
- Tire pressure monitoring
- Telemetry
- Personal/patient data logging
- Remote automatic meter reading



## DETAILED DESCRIPTION

The Si4020 FSK transmitter is designed to cover the unlicensed frequency bands at 315, 433, 868, and 915 MHz. The device facilitates compliance with FCC and ETSI requirements.

### PLL

The programmable PLL synthesizer determines the operating frequency, while preserving accuracy based on the on-chip crystal-controlled reference oscillator. The PLL's high resolution allows the usage of multiple channels in any of the bands. The FSK deviation is selectable (from 30 to 240 kHz with 30 kHz increments) to accommodate various bandwidth, data rate and crystal tolerance requirements, and it is also highly accurate due to the direct closed-loop modulation of the PLL. The transmitted digital data can be sent asynchronously through the FSK pin or over the control interface using the appropriate command.

The RF VCO in the PLL performs automatic calibration, which requires only a few microseconds. To ensure proper operation in the programmed frequency band, the RF VCO is automatically calibrated upon activation of the synthesizer. If temperature or supply voltage change significantly or operational band has changed, VCO recalibration is recommended. Recalibration can be initiated at any time by switching the synthesizer off and back on again.

### RF Power Amplifier (PA)

The power amplifier has an open-collector differential output and can directly drive a loop antenna with a programmable output power level. An automatic antenna tuning circuit is built in to avoid costly trimming procedures and the so-called "hand effect."

The transmitters can operate in On-Off Keying (OOK) mode by switching the power amplifier on and off. When the appropriate control bit is set using the Power Setting Command, the FSK pin becomes an enable input (active high) for the power amplifier.

### Crystal Oscillator

The chip has a single-pin crystal oscillator circuit, which provides a 10 MHz reference signal for the PLL. To reduce external parts and simplify design, the crystal load capacitor is internal and programmable. Guidelines for selecting the appropriate crystal can be found later in this datasheet.

The transmitters can supply the clock signal for the microcontroller, so accurate timing is possible without the need for a second crystal. When the chip receives a Sleep Command from the microcontroller and turns itself off, it provides several further clock pulses ("clock tail") for the microcontroller to be able to go to idle or sleep mode. The length of the clock tail is programmable.

### Low Battery Voltage Detector

The low battery voltage detector circuit monitors the supply voltage and generates an interrupt if it falls below a programmable threshold level. The detector circuit has 50 mV hysteresis.

### Wake-Up Timer

The wake-up timer has very low current consumption (1.5 uA typical) and can be programmed from 1 ms to several days with an accuracy of  $\pm 5\%$ .

It calibrates itself to the crystal oscillator at every startup. When the oscillator is switched off, the calibration circuit switches on the crystal oscillator only long enough for a quick calibration (a few milliseconds) to facilitate accurate wake-up timing.

### Event Handling

In order to minimize current consumption, the device supports sleep mode. Active mode can be initiated by several wake-up events: timeout of wake-up timer, detection of low supply voltage, pressing any of the four push-button inputs, or through the serial interface. The push-button inputs can be driven by a logic signal from a microcontroller or controlled directly by normally open switches. Pull-up resistors are integrated.

If any wake-up event occurs, the wake-up logic generates an interrupt, which can be used to wake up the microcontroller, effectively reducing the period the microcontroller has to be active. The cause of the interrupt can be read out from the transmitters by the microcontroller through the nIRQ pin.

### Interface

An SPI compatible serial interface lets the user select the operating frequency band and center frequency of the synthesizer, polarity and deviation of FSK modulation, and output power level. Division ratio for the microcontroller clock, wake-up timer period, and low battery detector threshold are also programmable. Any of these auxiliary functions can be disabled when not needed. All parameters are set to default after power-on; the programmed values are retained during sleep mode.

### EEPROM Mode

In simple applications, the on-chip digital controller provides the transmitters with direct interface to a serial (SPI) EEPROM. In this case, no external microcontroller is necessary. Wake-up events initiate automatic readout of the assigned command sequence from EEPROM memory. For every event, there is a dedicated starting address available in the EEPROM.

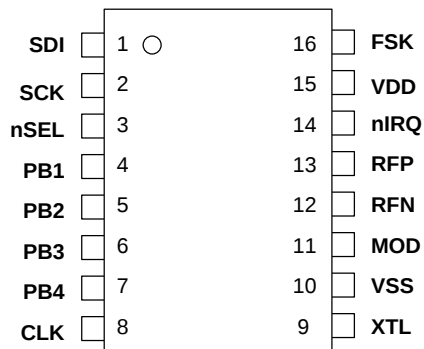
Programming the EEPROM is very simple. Any control command can be programmed in the EEPROM sequentially (same as in microcontroller mode).

The internal power-on reset (POR) is a dedicated event, which can be used to program the basic settings of the transmitters. In this case the chip starts to read out the preprogrammed data from the 00h address in EEPROM. Data can be transmitted with the help of the Data Transmit Command, which tells the transmitters how many bytes must be transmitted. The whole process finishes with a Sleep Command.

## PACKAGE PIN DEFINITIONS, MICROCONTROLLER MODE

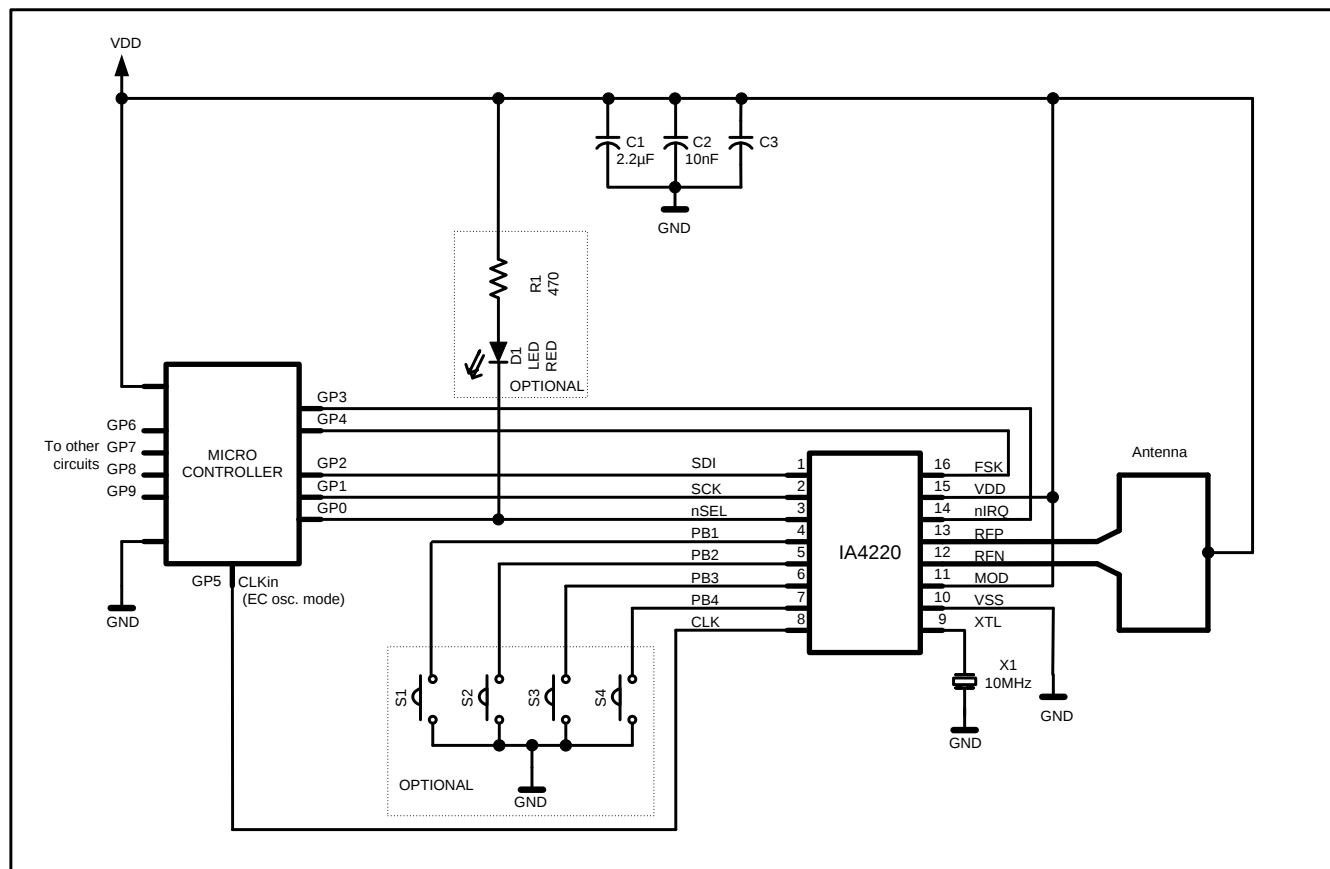
Pin type key: D=digital, A=analog, S=supply, I=input, O=output, IO=input/output

### Microcontroller Mode Pin Assignment



| Pin | Name | Type | Function                                                                         |
|-----|------|------|----------------------------------------------------------------------------------|
| 1   | SDI  | DI   | Data input of serial control interface                                           |
| 2   | SCK  | DI   | Clock input of serial control interface                                          |
| 3   | nSEL | DI   | Chip select input of serial control interface (active low)                       |
| 4   | PB1  | DI   | Push-button input #1 (active low with internal pull-up resistor)                 |
| 5   | PB2  | DI   | Push-button input #2 (active low with internal pull-up resistor)                 |
| 6   | PB3  | DI   | Push-button input #3 (active low with internal pull-up resistor)                 |
| 7   | PB4  | DI   | Push-button input #4 (active low with internal pull-up resistor)                 |
| 8   | CLK  | DO   | Microcontroller clock (1 MHz-10 MHz)                                             |
| 9   | XTL  | AIO  | Crystal connection (other terminal of crystal to VSS)                            |
| 10  | VSS  | S    | Ground reference                                                                 |
| 11  | MOD  | DI   | Connect to logic high (microcontroller mode)                                     |
| 12  | RFN  | AO   | Power amplifier output (open collector)                                          |
| 13  | RFP  | AO   | Power amplifier output (open collector)                                          |
| 14  | nIRQ | DO   | Interrupt request output for microcontroller (active low) and status read output |
| 15  | VDD  | S    | Positive supply voltage                                                          |
| 16  | FSK  | DI   | Serial data input for FSK modulation                                             |

### Typical Application, Microcontroller Mode

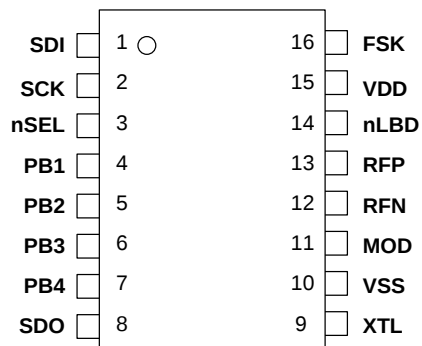


**Note:** For detailed information about the supply decoupling capacitors see page 6.

## PACKAGE PIN DEFINITIONS, EEPROM MODE

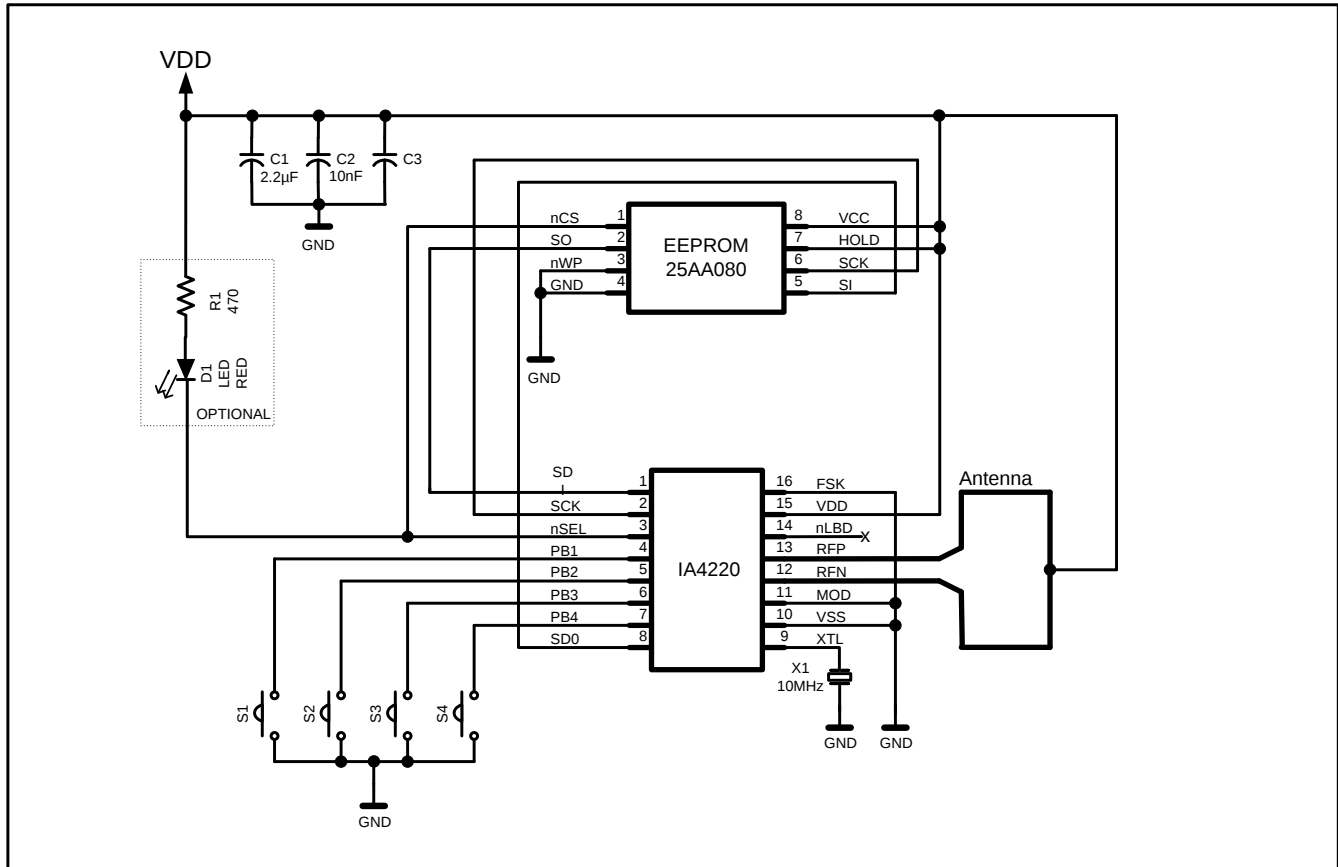
Pin type key: D=digital, A=analog, S=supply, I=input, O=output, IO=input/output

### EEPROM Mode Pin Assignment



| Pin | Name | Type | Function                                                         |
|-----|------|------|------------------------------------------------------------------|
| 1   | SDI  | DI   | Data input of serial control interface                           |
| 2   | SCK  | DO   | Clock output of serial control interface                         |
| 3   | nSEL | DO   | Chip select output of serial control interface (active low)      |
| 4   | PB1  | DI   | Push-button input #1 (active low with internal pull-up resistor) |
| 5   | PB2  | DI   | Push-button input #2 (active low with internal pull-up resistor) |
| 6   | PB3  | DI   | Push-button input #3 (active low with internal pull-up resistor) |
| 7   | PB4  | DI   | Push-button input #4 (active low with internal pull-up resistor) |
| 8   | SDO  | DO   | Data output of serial control interface                          |
| 9   | XTL  | AIO  | Crystal connection (other terminal of crystal to VSS)            |
| 10  | VSS  | S    | Ground reference                                                 |
| 11  | MOD  | DI   | Connect to logic low (EEPROM mode)                               |
| 12  | RFN  | AO   | Power amplifier output (open collector)                          |
| 13  | RFP  | AO   | Power amplifier output (open collector)                          |
| 14  | nLBD | DO   | Low battery voltage detector output (active low)                 |
| 15  | VDD  | S    | Positive supply voltage                                          |
| 16  | FSK  | DI   | Not used, connect to VDD or VSS                                  |

### Typical Application, EEPROM Mode



### Recommended supply decoupling capacitor values

C2 and C3 should be 0603 size ceramic capacitors to achieve the best supply decoupling. The capacitor values are valid for both stand-alone and microcontroller mode.

| Band [MHz] | C1    | C2   | C3    |
|------------|-------|------|-------|
| 315        | 2.2µF | 10nF | 390pF |
| 433        | 2.2µF | 10nF | 220pF |
| 868        | 2.2µF | 10nF | 47pF  |
| 915        | 2.2µF | 10nF | 33pF  |

## GENERAL DEVICE SPECIFICATIONS

All voltages are referenced to  $V_{SS}$ , the potential on the ground reference pin VSS.

### Absolute Maximum Ratings (non-operating)

| Symbol   | Parameter                                        | Min  | Max          | Units |
|----------|--------------------------------------------------|------|--------------|-------|
| $V_{dd}$ | Positive supply voltage                          | -0.5 | 6.0          | V     |
| $V_{in}$ | Voltage on any pin except open collector outputs | -0.5 | $V_{dd}+0.5$ | V     |
| $V_{oc}$ | Voltage on open collector outputs                | -0.5 | 6.0          | V     |
| $I_{in}$ | Input current into any pin except VDD and VSS    | -25  | 25           | mA    |
| ESD      | Electrostatic discharge with human body model    |      | 1000         | V     |
| $T_{st}$ | Storage temperature                              | -55  | 125          | °C    |
| $T_{ld}$ | Lead temperature (soldering, max 10 s)           |      | 260          | °C    |

### Recommended Operating Range

| Symbol   | Parameter                                     | Min          | Max          | Units |
|----------|-----------------------------------------------|--------------|--------------|-------|
| $V_{dd}$ | Positive supply voltage                       | 2.2          | 5.4          | V     |
| $V_{oc}$ | Voltage on open collector outputs (Max 6.0 V) | $V_{dd} - 1$ | $V_{dd} + 1$ | V     |
| $T_{op}$ | Ambient operating temperature                 | -40          | 85           | °C    |

## ELECTRICAL SPECIFICATION

(Min/max values are valid over the whole recommended operating range, typical conditions:  $T_{op} = 27\text{ °C}$ ;  $V_{dd} = V_{oc} = 2.7\text{ V}$ )

### DC Characteristics

| Symbol             | Parameter                                              | Conditions/Notes                            | Min                | Typ | Max                | Units |
|--------------------|--------------------------------------------------------|---------------------------------------------|--------------------|-----|--------------------|-------|
| $I_{dd\_TX\_0}$    | Supply current<br>(TX mode, $P_{out} = 0\text{ dBm}$ ) | 315 MHz band                                |                    | 9   |                    | mA    |
|                    |                                                        | 433 MHz band                                |                    | 10  |                    |       |
|                    |                                                        | 868 MHz band                                |                    | 12  |                    |       |
|                    |                                                        | 915 MHz band                                |                    | 13  |                    |       |
| $I_{dd\_TX\_PMAX}$ | Supply current<br>(TX mode, $P_{out} = P_{max}$ )      | 315 MHz band                                |                    | 11  |                    | mA    |
|                    |                                                        | 433 MHz band                                |                    | 12  |                    |       |
|                    |                                                        | 868 MHz band                                |                    | 14  |                    |       |
|                    |                                                        | 915 MHz band                                |                    | 15  |                    |       |
| $I_{pd}$           | Standby current in sleep mode                          | All blocks disabled (Note 1)                |                    | 0.3 |                    | μA    |
| $I_{wt}$           | Wake-up timer current consumption                      |                                             |                    | 1.5 |                    | μA    |
| $I_{lb}$           | Low battery detector current consumption               |                                             |                    | 0.5 |                    | μA    |
| $I_x$              | Idle current                                           | Only crystal oscillator is on               |                    | 1.5 |                    | mA    |
| $V_{lba}$          | Low battery detection accuracy                         |                                             |                    | 75  |                    | mV    |
| $V_{lb}$           | Low battery detector threshold                         | Programmable in 0.1 V steps                 | 2.2                |     | 5.3                | V     |
| $V_{il}$           | Digital input low level                                |                                             |                    |     | $0.3 \cdot V_{dd}$ | V     |
| $V_{ih}$           | Digital input high level                               |                                             | $0.7 \cdot V_{dd}$ |     |                    | V     |
| $I_{il}$           | Digital input current                                  | $V_{il} = 0\text{ V}$                       | -1                 |     | 1                  | μA    |
| $I_{ih}$           | Digital input current                                  | $V_{ih} = V_{dd}$ , $V_{dd} = 5.4\text{ V}$ | -1                 |     | 1                  | μA    |
| $V_{ol}$           | Digital output low level                               | $I_{ol} = 2\text{ mA}$                      |                    |     | 0.4                | V     |
| $V_{oh}$           | Digital output high level                              | $I_{oh} = -2\text{ mA}$                     | $V_{dd}-0.4$       |     |                    | V     |

Note for table above is on page 7.

**AC Characteristics**

| Symbol        | Parameter                                                        | Conditions/Notes                                                                    | Min          | Typ    | Max            | Units   |
|---------------|------------------------------------------------------------------|-------------------------------------------------------------------------------------|--------------|--------|----------------|---------|
| $f_{ref}$     | PLL reference frequency                                          | Crystal operation mode is parallel (Note 2)                                         | 8            | 10     | 12             | MHz     |
| $f_o$         | Output frequency (programmable)                                  | 315 MHz band, 2.5 kHz resolution                                                    | 310.24       |        | 319.75         | MHz     |
|               |                                                                  | 433 MHz band, 2.5 kHz resolution                                                    | 430.24       |        | 439.75         |         |
|               |                                                                  | 868 MHz band, 5.0 kHz resolution                                                    | 860.48       |        | 879.51         |         |
|               |                                                                  | 915 MHz band, 7.5 kHz resolution                                                    | 900.72       |        | 929.27         |         |
| $t_{lock}$    | PLL lock time                                                    | Frequency error < 10 kHz after 10 MHz step                                          |              | 20     |                | $\mu$ s |
| $t_{sp}$      | PLL startup time                                                 | After turning on from idle mode, with crystal oscillator already stable             |              |        | 250            | $\mu$ s |
| $I_{OUT}$     | Open collector output current (Note 3)                           | At all bands                                                                        | 0.1          |        | 2.5            | mA      |
| $P_{maxL}$    | Available output power (315 and 433 MHz band)                    | With optimal antenna impedance (Note 4)                                             |              | 3      |                | dBm     |
| $P_{maxH}$    | Available output power (868 and 915 MHz band)                    | With optimal antenna impedance (Note 4)                                             |              | 1      |                | dBm     |
| $P_{out}$     | Typical output power                                             | Selectable in 3 dB steps (Note3)                                                    | $P_{max}-21$ |        | $P_{max}$      | dBm     |
| $P_{sp}$      | Spurious emission                                                | At max power with loop antenna (Note 5)                                             |              |        | -50            | dBc     |
| $C_o$         | Output capacitance (set by the automatic antenna tuning circuit) | At low bands                                                                        | 1.5          | 2.3    | 3.1            | pF      |
|               |                                                                  | At high bands                                                                       | 1.6          | 2.2    | 2.8            |         |
| $Q_o$         | Quality factor of the output capacitance                         |                                                                                     | 16           | 18     | 22             |         |
| $L_{out}$     | Output phase noise                                               | 100 kHz from carrier                                                                |              | -75    |                | dBc/Hz  |
|               |                                                                  | 1 MHz from carrier                                                                  |              | -85    |                |         |
| $BR_{FSK}$    | FSK bit rate                                                     |                                                                                     |              |        | 256            | kbps    |
| $BR_{OOK}$    | OOK bit rate                                                     |                                                                                     |              |        | 512            | kbps    |
| $df_{fsk}$    | FSK frequency deviation                                          | Programmable in 30 kHz steps                                                        | 30           |        | 240            | kHz     |
| $C_{xl}$      | Crystal load capacitance<br>See Crystal Selection Guidelines     | Programmable in 0.5 pF steps, tolerance +/- 10%                                     | 8.5          |        | 16             | pF      |
| $t_{POR}$     | Internal POR timeout (Note 6)                                    | After $V_{dd}$ has reached 90% of final value                                       |              |        | 100            | ms      |
| $t_{sx}$      | Crystal oscillator startup time                                  | Crystal ESR < 100 Ohms (Note 7)                                                     |              | 1      | 5              | ms      |
| $t_{PBT}$     | Wake-up timer clock accuracy                                     | Crystal oscillator must be enabled to ensure proper calibration at startup (Note 7) |              | +/-10% |                | ms      |
| $t_{wake-up}$ | Programmable wake-up time                                        |                                                                                     | 1            |        | $2 \cdot 10^9$ | ms      |
| $C_{in,D}$    | Digital input capacitance                                        |                                                                                     |              |        | 2              | pF      |
| $t_{r,f}$     | Digital output rise/fall time                                    | 15 pF pure capacitive load                                                          |              |        | 10             | ns      |

All notes for table above are on page 7.

**Note 1:** Using a CR2032 battery (225 mAh capacity), the expected battery life is greater than 2 years using a 60-second wake-up period for sending 100 byte packets in length at 19.2 kbps with +3 dBm output power in the 915 MHz band.

**Note 2:** Using anything but a 10 MHz crystal is allowed but not recommended because all crystal-referred timing and frequency parameters will change accordingly.

**Note 3:** Adjustable in 8 steps.

**Note 4:** Optimal antenna admittance/impedance for the Si4020:

|                | Yantenna [S]      | Zantenna [Ohm] | Lantenna [nH] |
|----------------|-------------------|----------------|---------------|
| <b>315 MHz</b> | 9.4E-4 - j4.5E-3  | 43 + j214      | 112.00        |
| <b>434 MHz</b> | 8.4E-4 - j6.25E-3 | 21 + j157      | 59.00         |
| <b>868 MHz</b> | 1.15E-3 - j1.2E-2 | 7.9 + j83      | 15.30         |
| <b>915 MHz</b> | 1.2E-3 - j1.25E-2 | 7.6 + j79      | 13.90         |

**Note 5:** With selective resonant antennas (see: Application Notes available from <http://www.silabs.com/integration>).

**Note 6:** During this period, no commands are accepted by the chip. For detailed information see the *Reset modes* section.

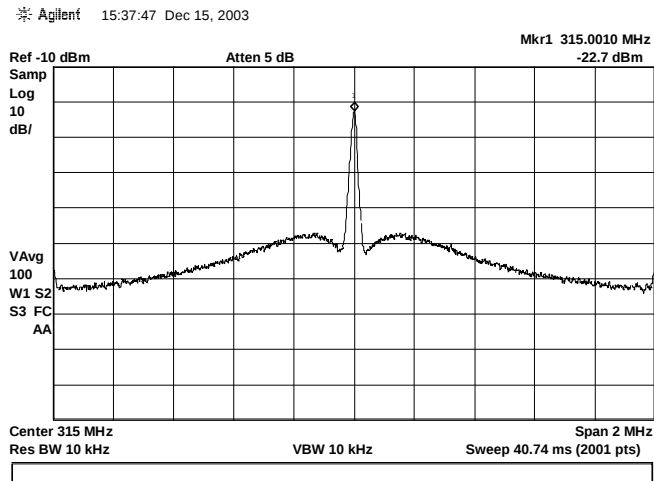
**Note 7:** The crystal oscillator start-up time strongly depends on the capacitance seen by the oscillator. Using low capacitance and low ESR crystal is recommended. When designing the PCB layout keep the trace connecting to the crystal short to minimize stray capacitance.

## TYPICAL PERFORMANCE DATA

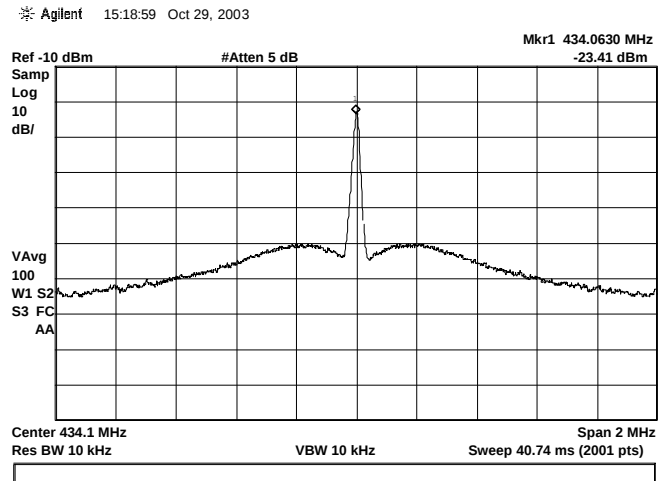
### Unmodulated RF Spectrum

The output spectrum is measured at different frequencies. The output is loaded with 50 Ohms through a matching network.

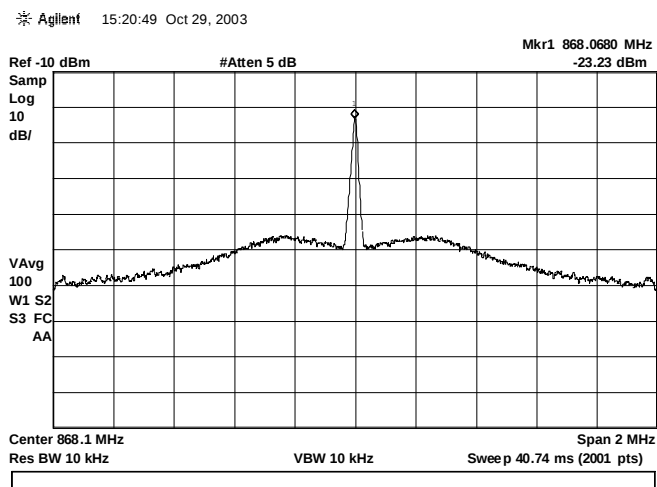
**At 315 MHz**



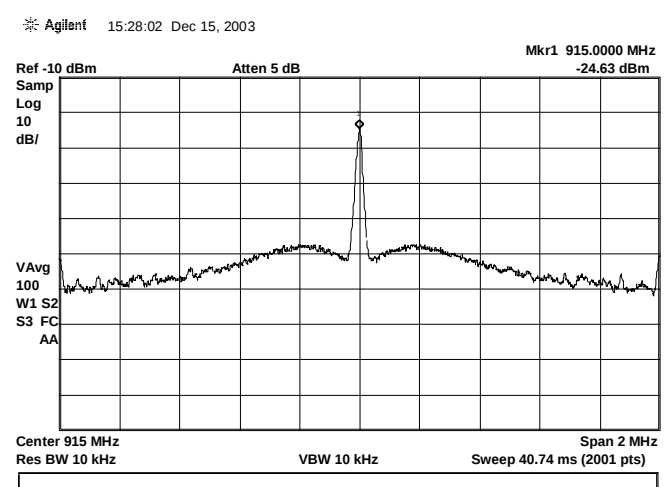
**At 433 MHz**



**At 868 MHz**



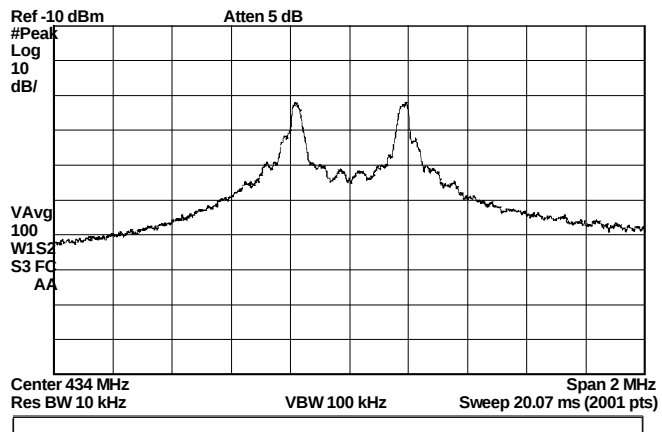
**At 915 MHz**



## Modulated RF Spectrum

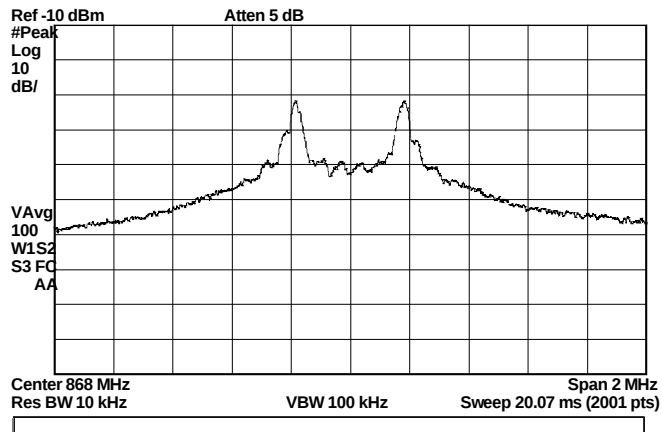
**At 433 MHz with  
180 kHz Deviation at 64 kbps**

Agilent 15:46:09 Oct 29, 2003



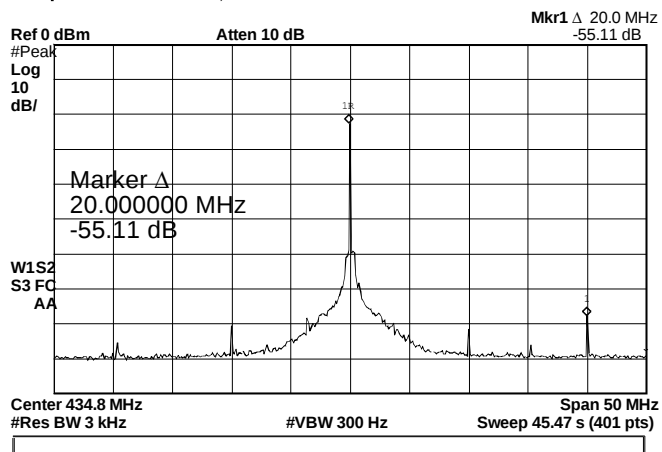
**At 868 MHz with  
180 kHz Deviation at 64 kbps**

Agilent 15:43:45 Oct 29, 2003



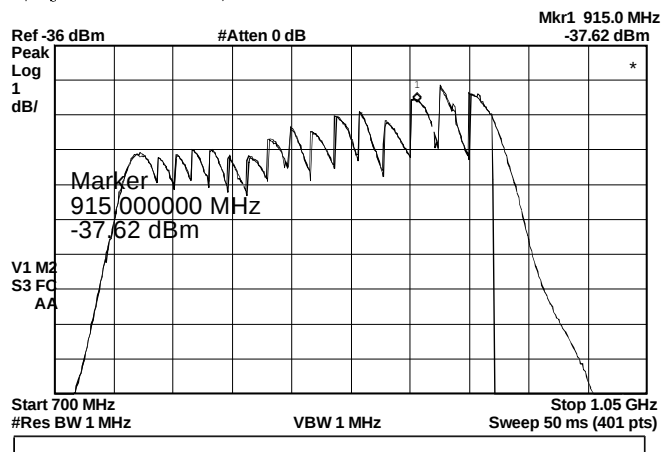
**Spurious RF Spectrum  
With 10 MHz CLK Output Enabled at 433 MHz**

Agilent 16:29:03 Jun 17, 2003



**Antenna Tuning Characteristics  
750–970 MHz**

Agilent 16:54:54 Mar 11, 2003



The antenna tuning characteristics was recorded in “max-hold” state of the spectrum analyzer. During the measurement, the transmitters were forced to change frequencies by forcing an external reference signal to the XTL pin. While the carrier was changing the antenna tuning circuit switched through all the available states of the tuning circuit. The graph clearly demonstrates that while the complete output circuit had about a 40 MHz bandwidth, the tuning allows operating in a 220 MHz band. In other words the tuning circuit can compensate for 25% variation in the resonant frequency due to any process or manufacturing spread.

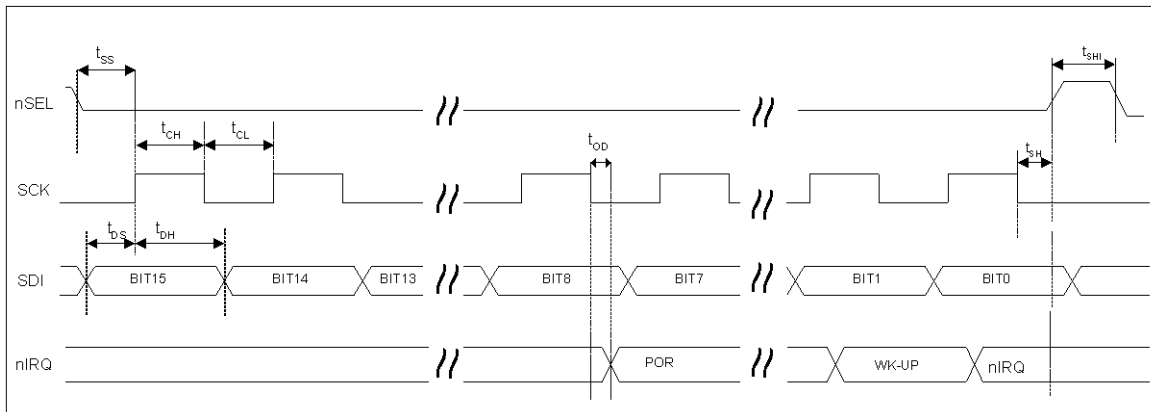
## CONTROL INTERFACE

Commands to the transmitters are sent serially. Data bits on pin SDI are shifted into the device upon the rising edge of the clock on pin SCK whenever the chip select pin nSEL is low. When the nSEL signal is high, it initializes the serial interface. The number of bits sent is an integer multiple of 8. All commands consist of a command code, followed by a varying number of parameter or data bits. All data are sent MSB first (e.g. bit 15 for a 16-bit command). Bits having no influence (don't care) are indicated with X. The Power On Reset (POR) circuit sets default values in all control and command registers.

### Timing Specification

| Symbol    | Parameter                                                | Minimum value [ns] |
|-----------|----------------------------------------------------------|--------------------|
| $t_{CH}$  | Clock high time                                          | 25                 |
| $t_{CL}$  | Clock low time                                           | 25                 |
| $t_{SS}$  | Select setup time (nSEL falling edge to SCK rising edge) | 10                 |
| $t_{SH}$  | Select hold time (SCK falling edge to nSEL rising edge)  | 10                 |
| $t_{SHI}$ | Select high time                                         | 25                 |
| $t_{DS}$  | Data setup time (SDI transition to SCK rising edge)      | 5                  |
| $t_{DH}$  | Data hold time (SCK rising edge to SDI transition)       | 5                  |
| $t_{OD}$  | Data delay time                                          | 10                 |
| $t_{BL}$  | Push-button input low time                               | 25                 |

### Timing Diagram



## Control Commands

|    | Control Command               | Related Parameters/Functions                                                                               |
|----|-------------------------------|------------------------------------------------------------------------------------------------------------|
| 1  | Configuration Setting Command | Frequency band, microcontroller clock output, crystal load capacitance, frequency deviation                |
| 2  | Power Management Command      | Crystal oscillator, synthesizer, power amplifier, low battery detector, wake-up timer, clock output buffer |
| 3  | Frequency Setting Command     | Carrier frequency                                                                                          |
| 4  | Data Rate Command             | Bit rate (at EEPROM mode only)                                                                             |
| 5  | Power Setting Command         | Nominal output power, OOK mode                                                                             |
| 6  | Low Battery Detector Command  | Low battery threshold limit                                                                                |
| 7  | Sleep Command                 | Length of the clock tail after power down                                                                  |
| 8  | Push-Button Command           | Push-button related functions                                                                              |
| 9  | Wake-Up Timer Command         | Wake-up time period                                                                                        |
| 10 | Data Transmit Command         | Data transmission                                                                                          |
| 11 | Status Register Command       | Transmitter status read                                                                                    |

**Note:** In the following tables the POR column shows the default values of the command registers after power-on.

### 1. Configuration Setting Command

| bit | 15 | 14 | 13 | 12 | 11 | 10 | 9  | 8  | 7  | 6  | 5  | 4  | 3  | 2  | 1  | 0  | POR   |
|-----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|-------|
|     | 1  | 0  | 0  | b1 | b0 | d2 | d1 | d0 | x3 | x2 | x1 | x0 | ms | m2 | m1 | m0 | 8080h |

| b1 | b0 | Frequency Band [MHz] |
|----|----|----------------------|
| 0  | 0  | 315                  |
| 0  | 1  | 433                  |
| 1  | 0  | 868                  |
| 1  | 1  | 915                  |

| d2 | d1 | d0 | Clock Output Frequency [MHz] |
|----|----|----|------------------------------|
| 0  | 0  | 0  | 1                            |
| 0  | 0  | 1  | 1.25                         |
| 0  | 1  | 0  | 1.66                         |
| 0  | 1  | 1  | 2                            |
| 1  | 0  | 0  | 2.5                          |
| 1  | 0  | 1  | 3.33                         |
| 1  | 1  | 0  | 5                            |
| 1  | 1  | 1  | 10                           |

| x3  | x2 | x1 | x0 | Crystal Load Capacitance [pF] |
|-----|----|----|----|-------------------------------|
| 0   | 0  | 0  | 0  | 8.5                           |
| 0   | 0  | 0  | 1  | 9.0                           |
| 0   | 0  | 1  | 0  | 9.5                           |
| 0   | 0  | 1  | 1  | 10.0                          |
| ... |    |    |    |                               |
| 1   | 1  | 1  | 0  | 15.5                          |
| 1   | 1  | 1  | 1  | 16.0                          |

The resulting output frequency can be calculated as:

$$f_{\text{out}} = f_0 - (-1)^{\text{SIGN}} * (M + 1) * (30 \text{ kHz})$$

where:

$f_0$  is the channel center frequency (see the next command)

M is the three bit binary number <m2 : m0>

SIGN = (ms) XOR (FSK input)

## 2. Power Management Command

| bit | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7  | 6  | 5  | 4  | 3  | 2  | 1  | 0  | POR   |
|-----|----|----|----|----|----|----|---|---|----|----|----|----|----|----|----|----|-------|
|     | 1  | 1  | 0  | 0  | 0  | 0  | 0 | 0 | a1 | a0 | ex | es | ea | eb | et | dc | C000h |

Bits 5-0, enable the corresponding block of the transmitters, i.e. the crystal oscillator is enabled by the *ex* bit, the synthesizer by *es*, the power amplifier by *ea* and the low battery detector by *eb*, while the wake-up timer by *et*. The bit *dc* disables the clock output buffer.

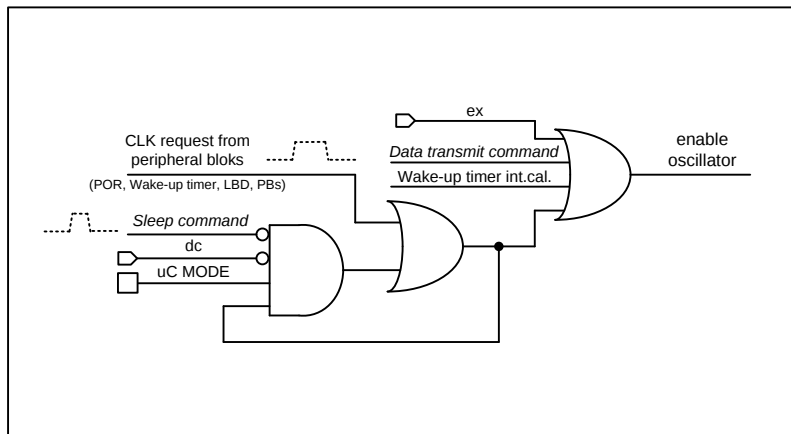
When receiving the *Data Transmit Command*, the chip supports automatic on/off control over the crystal oscillator, the PLL and the PA.

If bit *a1* is set, the crystal oscillator and the synthesizer are controlled automatically. *Data Transmit Command* starts up the crystal oscillator and as soon as a stable reference frequency is available the synthesizer starts. After a subsequent delay to allow locking of the PLL, if *a0* is set the power amplifier is turned on as well.

### Note:

- To enable the automatic internal control of the crystal oscillator, the synthesizer and the power amplifier, the corresponding bits (*ex*, *es*, *ea*) must be zero in the *Power Management Command*.
- In microcontroller mode, the *ex* bit should be set in the *Power Management Command* for the correct control of *es* and *ea*. The oscillator can be switched off by clearing the *ex* bit after the transmission.
- In EEPROM operation mode after an identified *Data Transmit Command* the internal logic switches on the synthesizer and PA. At the end of *Data Transmit Command* header if necessary the current clock cycle is automatically extended to ensure the PLL stabilization and RF power ramp-up.
- In EEPROM operation mode the internal logic switches off the PA when the given number of bytes is transmitted. (See: *Data Transmit Command* in EEPROM operation.)
- When the chip is controlled by a microcontroller, the *Sleep Command* can be used to indicate the end of the data transmission process, because in microcontroller mode the *Data Transmit Command* does not contain the length of the TX data.
- For processing the events caused by the peripheral blocks (POR, LBD, wake-up timer, push-buttons) the chip requires operation of the crystal oscillator. This operation is fully controlled internally, independently from the status of the *ex* bit, but if the *dc* bit is zero, the oscillator remains active until *Sleep Command* is issued. (This command can be considered as an event controller reset.)

### Oscillator control logic



### 3. Frequency Setting Command

| bit | 15 | 14 | 13 | 12 | 11  | 10  | 9  | 8  | 7  | 6  | 5  | 4  | 3  | 2  | 1  | 0  | POR   |
|-----|----|----|----|----|-----|-----|----|----|----|----|----|----|----|----|----|----|-------|
|     | 1  | 0  | 1  | 0  | f11 | f10 | f9 | f8 | f7 | f6 | f5 | f4 | f3 | f2 | f1 | f0 | A7D0h |

The 12-bit parameter of the *Frequency Setting Command* <f11 : f0> has the value F. The value F should be in the range of 96 and 3903. When F is out of range, the previous value is kept. The synthesizer center frequency  $f_0$  can be calculated as:

$$f_0 = 10 \text{ MHz} * C1 * (C2 + F/4000)$$

The constants C1 and C2 are determined by the selected band as:

| Band [MHz] | C1 | C2 |
|------------|----|----|
| 315        | 1  | 31 |
| 433        | 1  | 43 |
| 868        | 2  | 43 |
| 915        | 3  | 30 |

#### Note:

- For correct operation of the frequency synthesizer, the frequency and band of operation need to be programmed **before** the synthesizer is started. Directly after activation of the synthesizer, the RF VCO is calibrated to ensure proper operation in the programmed frequency band.
- When coding for the Si4020, it is suggested that recalibration routines be added to compensate for significant changes in temperature and supply voltages.

### 4. Data Rate Command

| bit | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7  | 6  | 5  | 4  | 3  | 2  | 1  | 0  | POR   |
|-----|----|----|----|----|----|----|---|---|----|----|----|----|----|----|----|----|-------|
|     | 1  | 1  | 0  | 0  | 1  | 0  | 0 | 0 | r7 | r6 | r5 | r4 | r3 | r2 | r1 | r0 | C800h |

In EEPROM mode the transmitted bit rate is determined by the 8-bit value R (bits <r7 : r0>) as:

$$BR = 10 \text{ MHz} / 29 / (R+1)$$

Apart from setting custom values, the standard bit rates from 2.4 to 115.2 kbps can be approximated with minimal error. The commands are read out with a different fixed bit rate:

$$F_{sck} = 10 \text{ MHz} / 29 / 3 [\sim 115.2 \text{ kHz}]$$

### 5. Power Setting Command

| bit | 7 | 6 | 5 | 4 | 3   | 2  | 1  | 0  | POR |
|-----|---|---|---|---|-----|----|----|----|-----|
|     | 1 | 0 | 1 | 1 | ook | p2 | p1 | p0 | B0h |

The bit ook enables the OOK mode for the PA, in this case the data to be transmitted are received through the FSK pin.

| p2 | p1 | p0 | Relative Output Power [dB] |
|----|----|----|----------------------------|
| 0  | 0  | 0  | 0                          |
| 0  | 0  | 1  | -3                         |
| 0  | 1  | 0  | -6                         |
| 0  | 1  | 1  | -9                         |
| 1  | 0  | 0  | -12                        |
| 1  | 0  | 1  | -15                        |
| 1  | 1  | 0  | -18                        |
| 1  | 1  | 1  | -21                        |

The output power is given in the table as relative to the maximum available power, which depends on the actual antenna impedance. (See: Antenna Application Note available from [www.silabs.com/integration](http://www.silabs.com/integration)).

## 6. Low Battery Detector Command

| bit | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4  | 3  | 2  | 1  | 0  | POR   |
|-----|----|----|----|----|----|----|---|---|---|---|---|----|----|----|----|----|-------|
|     | 1  | 1  | 0  | 0  | 0  | 0  | 1 | 0 | 0 | 0 | 0 | t4 | t3 | t2 | t1 | t0 | C200h |

The 5-bit value T of <t4 : t0> determines the threshold voltage  $V_{lb}$  of the detector:

$$V_{lb} = 2.25 \text{ V} + T * 0.1 \text{ V}$$

## 7. Sleep Command

| bit | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7  | 6  | 5  | 4  | 3  | 2  | 1  | 0  | POR   |
|-----|----|----|----|----|----|----|---|---|----|----|----|----|----|----|----|----|-------|
|     | 1  | 1  | 0  | 0  | 0  | 1  | 0 | 0 | s7 | s6 | s5 | s4 | s3 | s2 | s1 | s0 | C400h |

The effect of this command depends on the *Power Management Command*. It immediately disables the power amplifier (if  $a0=1$  and  $ea=0$ ) and the synthesizer (if  $a1=1$  and  $es=0$ ). Stops the crystal oscillator after S periods of the microcontroller clock (if  $a1=1$  and  $ex=0$ ) to enable the microcontroller to execute all necessary commands before entering sleep mode itself. The 8-bit value S is determined by bits <s7 : s0>.

## 8. Push-Button Command

| bit | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7  | 6  | 5  | 4  | 3  | 2  | 1  | 0  | POR   |
|-----|----|----|----|----|----|----|---|---|----|----|----|----|----|----|----|----|-------|
|     | 1  | 1  | 0  | 0  | 1  | 0  | 1 | 0 | p4 | d1 | d0 | b4 | b3 | b2 | b1 | bc | CA00h |

If the corresponding bit was set (b1-b4) the event remains active while the button is pressed. In EEPROM mode, the chip is continuously performing the routine assigned to the push-button while it is pressed. In microcontroller mode, the chip continuously generates interrupts on nIRQ until the push-button is released. Weak pull-up currents are switched off when bc is high.

The d0, d1 bits set the de-bouncing time period:

| d1 | d0 | De-bouncing Time [ms] |
|----|----|-----------------------|
| 0  | 0  | 160                   |
| 0  | 1  | 40                    |
| 1  | 0  | 10                    |
| 1  | 1  | 0 (Bypassed)          |

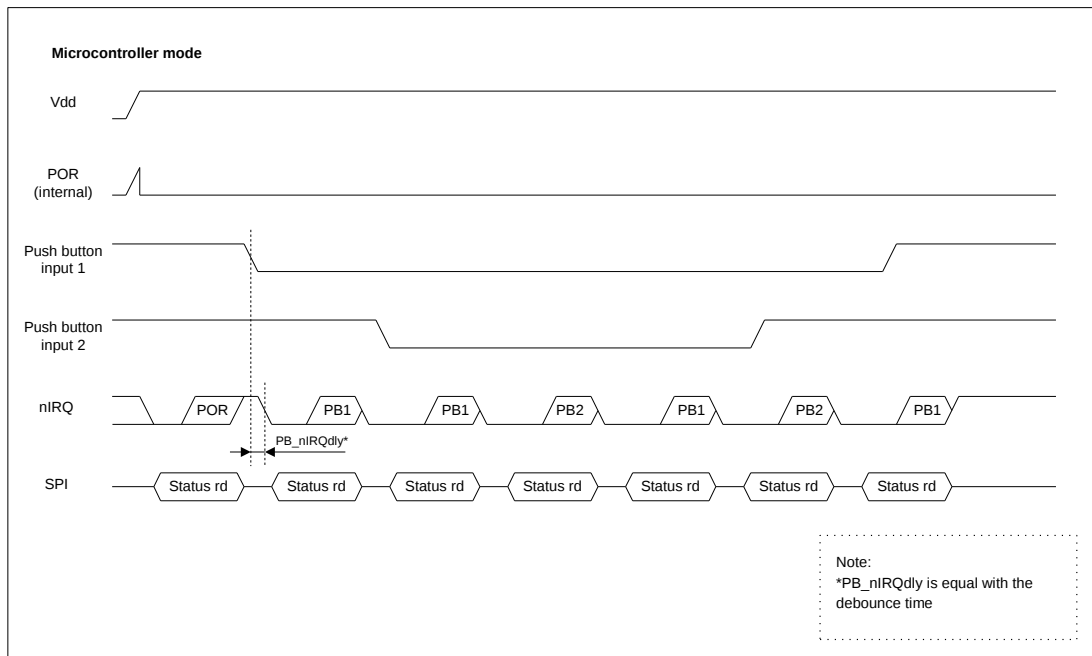
### Note:

- Until the de-bouncing time has expired, the crystal oscillator remains switched on, independent of the status of the ex bit in the *Power Management Command*. (Because the circuit uses the crystal oscillator signal for timing.)

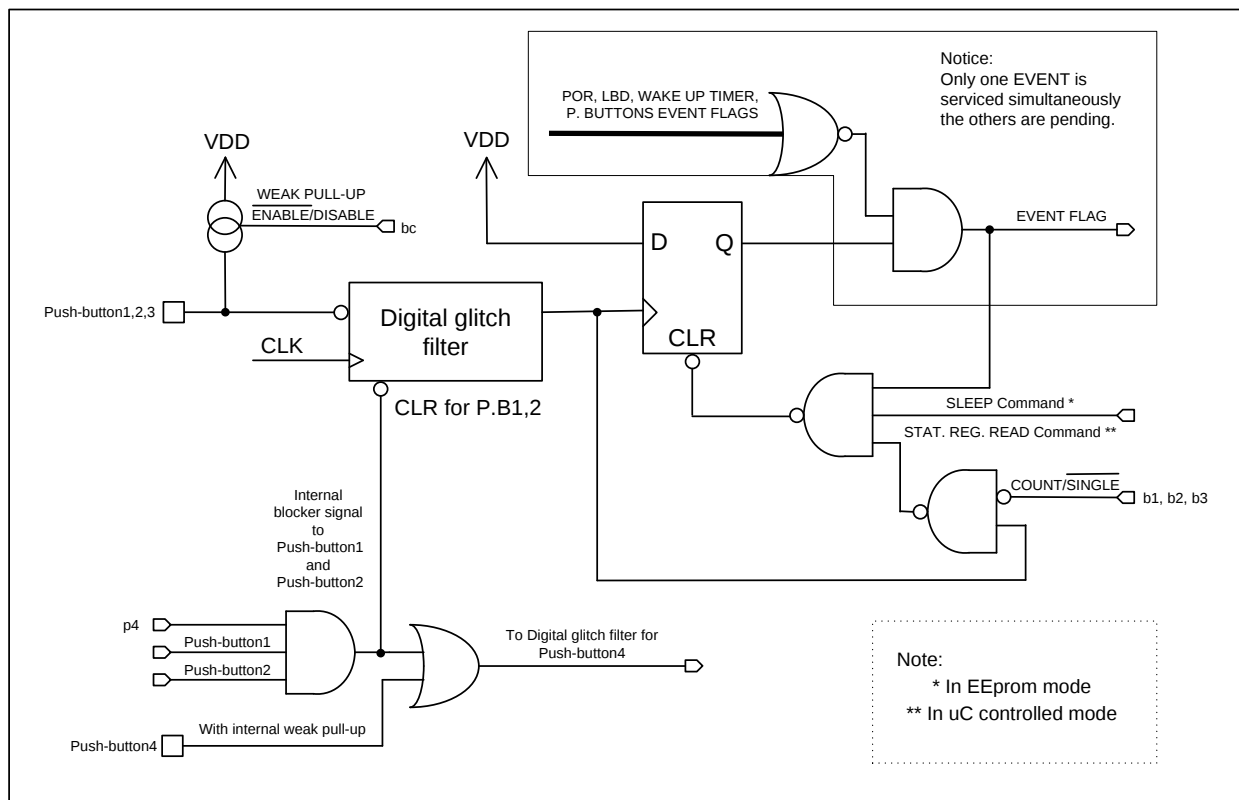
If the p4 bit is set, the controller performs the routine assigned to the fourth button when PB1 and PB2 are pressed down simultaneously. With the addition of this feature, there is a way to build a device that uses 3 buttons, but performs 4 functions.

It is possible to detect multiple pressed push-buttons in both modes. In EEPROM mode the controller executes sequentially all the routines belonging to the pressed buttons.

### Simultaneously Pressed Push-Button Detect by Microcontroller



### Simplified Block Diagram of Push-Button 1-4 Inputs



### 9. Wake-Up Timer Command

| bit | 15 | 14 | 13 | 12 | 11 | 10 | 9  | 8  | 7  | 6  | 5  | 4  | 3  | 2  | 1  | 0  | POR   |
|-----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|-------|
|     | 1  | 1  | 1  | r4 | r3 | r2 | r1 | r0 | m7 | m6 | m5 | m4 | m3 | m2 | m1 | m0 | E000h |

The wake-up time period can be calculated as:

$$T_{\text{wake-up}} = M * 2^R [\text{ms}] ,$$

where M is defined by the <m7 : m0> digital value and R is defined by the <r4 : r0> digital value.

The value of R should be in the range of 0 and 23. The maximum achievable wake-up time period can be up to 24 days.

**Note:**

- For continual operation the et bit should be cleared and set at the end of every cycle.

Software reset: Sending FF00h command to the chip triggers software reset. For more details see the *Reset modes* section.

### 10. Data Transmit Command

This command is not needed if the transmitters' power management bits (ex, es, ea) are fully controlled by the microcontroller and TX data comes through the FSK pin.

In EEPROM operation mode:

| bit | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7  | 6  | 5  | 4  | 3  | 2  | 1  | 0  | POR |
|-----|----|----|----|----|----|----|---|---|----|----|----|----|----|----|----|----|-----|
|     | 1  | 1  | 0  | 0  | 0  | 1  | 1 | 0 | n7 | n6 | n5 | n4 | n3 | n2 | n1 | n0 | --  |

In microcontroller slave mode:

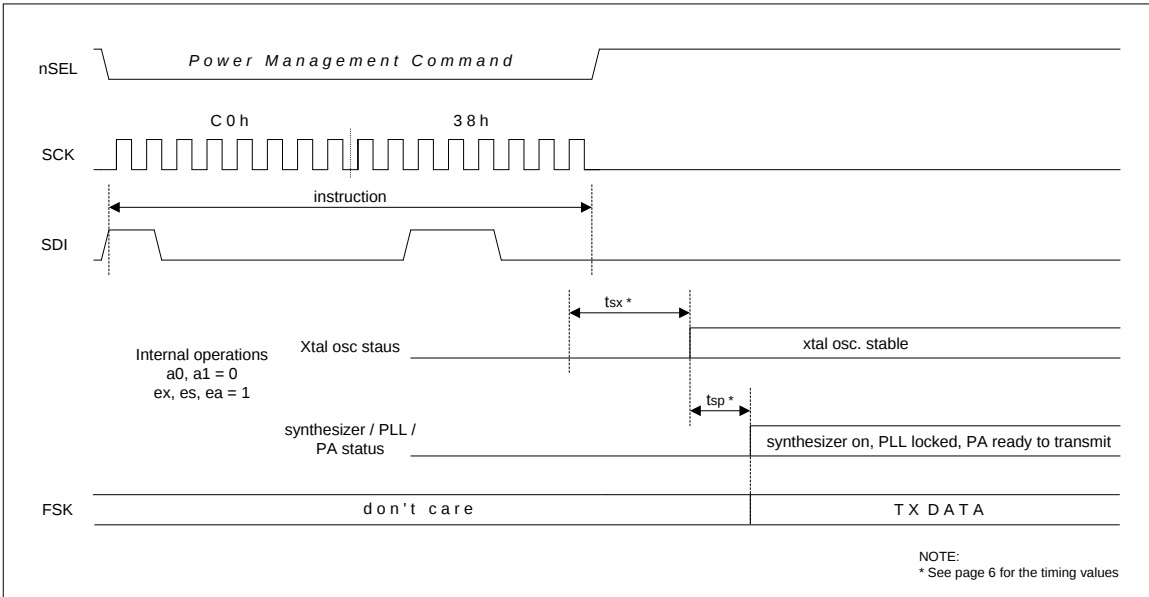
| bit | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | POR |
|-----|---|---|---|---|---|---|---|---|-----|
|     | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | --  |

This command indicates that the following bitstream coming in via the serial interface is to be transmitted. In EEPROM mode, the 8-bit value N of bits <n7 : n0> contains the number of data bytes to follow.

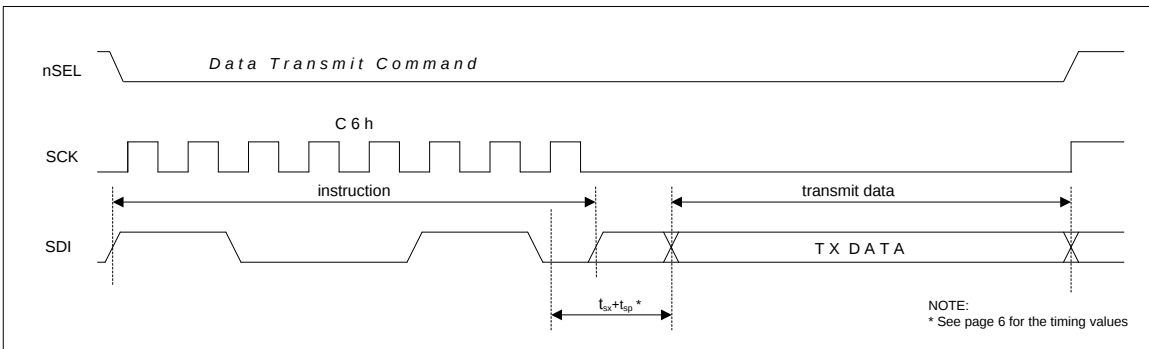
**Note:**

- If the crystal oscillator was formerly switched off (ex=0), the internal oscillator needs  $t_{sx}$  time, to switch on. The actual value depends on the type of quartz crystal used.
- If the synthesizer was formerly switched off (es=0), the internal PLL needs  $t_{sp}$  startup time. Valid data can be transmitted only when the internal locking process is finished.
- In EEPROM mode, before issuing the *Data Transmit Command*, the power amplifier must be enabled, with the ea or a0 bit in the *Power Management Command*.
- In EEPROM mode, when N bytes have been read and transmitted the controller continues reading the EEPROM and processing the data as control commands. This process stops after *Sleep Command* has been read from the EEPROM.

### Data Transmit Sequence Through the FSK Pin



### Data Transmit Sequence Through the SDI Pin



#### Note:

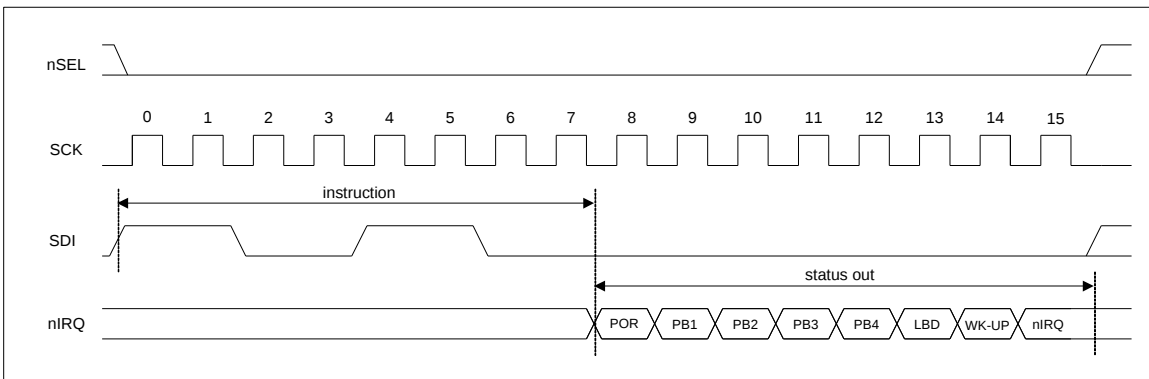
- Do not send CLK pulses with the TX data bits; otherwise they will be interpreted as commands.
- This mode is not SPI compatible, therefore it is not recommended in microcontroller mode.
- If the crystal oscillator and the PLL are running, the  $t_{sx} + t_{sp}$  delay is not needed.

### 11. Status Register Read Command

| bit | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | POR |
|-----|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|-----|
|     | 1  | 1  | 0  | 0  | 1  | 1  | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | --  |

With this command, it is possible to read the chip's status register through the nIRQ pin. This command clears the last serviced interrupt and processing the next pending one will start (if there is any).

#### Status Register Read Sequence



## EEPROM MODE

In this mode, the transmitters can operate with a standard at least 1 kbyte serial EEPROM with an SPI interface, and no microcontroller is necessary. The following events cause wake-up of the device:

| Event Number N | EEPROM entry point | Description              |
|----------------|--------------------|--------------------------|
| 0              | 0000h              | power-on                 |
| 1              | 0080h              | low level on input PB1   |
| 2              | 0100h              | low level on input PB2   |
| 3              | 0180h              | low level on input PB3   |
| 4              | 0200h              | low level on input PB4   |
| 5              | 0280h              | low supply voltage level |
| 6              | 0300h              | wake-up timer timeout    |

After any of these events, the crystal oscillator turns on and the device starts to read bytes from the EEPROM continuously (block read) starting from address  $N * 128$  (decimal) and executes them as commands as described in the previous section.

**Note:** Zero bytes can be put in the EEPROM for timing purposes. Never put more than 31 consecutive zero bytes into the EEPROM's active region (between the actual entry point and the closing Sleep Command).

### Example EEPROM Hex Content

#### Power-On Reset:

```

00000000  C0  C4  CA  1E  C8  23  C4  00  00  00  00  00  00  00  00  00
00000010  00  00  00  00  00  00  00  00  00  00  00  00  00  00  00
00000020  00  00  00  00  00  00  00  00  00  00  00  00  00  00  00
00000030  00  00  00  00  00  00  00  00  00  00  00  00  00  00  00
00000040  00  00  00  00  00  00  00  00  00  00  00  00  00  00  00
00000050  00  00  00  00  00  00  00  00  00  00  00  00  00  00  00
00000060  00  00  00  00  00  00  00  00  00  00  00  00  00  00  00
00000070  00  00  00  00  00  00  00  00  00  00  00  00  00  00  00

```

#### Short Explanation:

Data in Address, Command, and Parameter fields are hexadecimal values.

For the detailed description of the control command bits, see previous section.

| Address | Command | Parameter | Related Control Command | Remarks                                                         |
|---------|---------|-----------|-------------------------|-----------------------------------------------------------------|
| 00-01   | C0      | C4        | Power Management        | Crystal – Synthesizer – Power Amplifier auto on/off mode enable |
| 02-03   | CA      | 1E        | Push Button             | Continuous execution for all push buttons                       |
| 04-05   | C8      | 23        | Bit Rate                | $BR = 10M / 29 / (35+1) \sim 9600$ bps                          |
| 06-07   | C4      | 00        | Sleep                   | Power down                                                      |

**Push-button 1:**

```

00000080  88  72  A6  10  C6  60  55  55  55  55  55  55  55  55  55  55
00000090  55  55  55  55  55  55  55  55  55  55  55  55  55  55  55
000000A0  55  55  55  55  55  55  55  55  55  55  55  55  55  55  55
000000B0  55  55  55  55  55  55  55  55  55  55  55  55  55  55  55
000000C0  55  55  55  55  55  55  55  55  55  55  55  55  55  55  55
000000D0  55  55  55  55  55  55  55  55  55  55  55  55  55  55  55
000000E0  55  55  55  55  55  55  C4  00  00  00  00  00  00  00  00
000000F0  00  00  00  00  00  00  00  00  00  00  00  00  00  00  00

```

**Short Explanation:**

| Address | Command | Parameter | Related Control Command | Remarks                                                        |
|---------|---------|-----------|-------------------------|----------------------------------------------------------------|
| 80–81   | 8       | 872       | Configuration Control   | 433MHz band, Xtal C <sub>L</sub> =12pF f <sub>dev</sub> =90kHz |
| 82–83   | A       | 610       | Frequency               | $f_c = (43 + 1552/4000) * 10\text{MHz}$                        |
| 84–85   | C6      | 60        | Data Transmit           | Transmit the next 96 bytes                                     |
| 86–E5   |         | 60x55     |                         | Data                                                           |
| E6–E7   | C4      | 00        | Sleep                   | Power down, go to address 80 (see note)                        |

**Note:**

- This routine is repeatedly executed while PB1 is pressed, because continuous execution was selected at POR (CA1E code issued in the power-on reset section before).

**RX-TX ALIGNMENT PROCEDURES**

RX-TX frequency offset can be caused only by the differences in the actual reference frequency. To minimize these errors it is suggested to use the same crystal type and the same PCB layout for the crystal placement on the RX and TX PCBs.

To verify the possible RX-TX offset it is suggested to measure the CLK output of both chips with a high level of accuracy. Do not measure the output at the XTL pin since the measurement process itself will change the reference frequency. Since the carrier frequencies are derived from the reference frequency, having identical reference frequencies and nominal frequency settings at the TX and RX side there should be no offset if the CLK signals have identical frequencies.

It is possible to monitor the actual RX-TX offset using the AFC status report included in the status byte of the receiver. By reading out the status byte from the receiver, the actual measured offset frequency will be reported. In order to get accurate values the AFC has to be disabled during the read by clearing the "en" bit in the AFC Control Command (bit 0).

## CRYSTAL SELECTION GUIDELINES

The crystal oscillator of the Si4020 requires a 10 MHz parallel mode crystal. The circuit contains an integrated load capacitor in order to minimize the external component count. The internal load capacitance value is programmable from 8.5 pF to 16 pF in 0.5 pF steps. With appropriate PCB layout, the total load capacitance value can be 10 pF to 20 pF so a variety of crystal types can be used.

When the total load capacitance is not more than 20 pF and a worst case 7 pF shunt capacitance ( $C_0$ ) value is expected for the crystal, the oscillator is able to start up with any crystal having less than 300 ohms ESR (equivalent series loss resistance). However, lower  $C_0$  and ESR values guarantee faster oscillator startup.

The crystal frequency is used as the reference of the PLL, which generates the RF carrier frequency ( $f_c$ ). Therefore,  $f_c$  is directly proportional to the crystal frequency. The accuracy requirements for production tolerance, temperature drift and aging can thus be determined from the maximum allowable carrier frequency error.

### Maximum XTAL Tolerances Including Temperature and Aging [ppm]

| Bit Rate: 2.4kbps | Transmitter Deviation [± kHz] |    |     |     |     |     |     |
|-------------------|-------------------------------|----|-----|-----|-----|-----|-----|
|                   | 30                            | 60 | 90  | 120 | 150 | 180 | 210 |
| 315 MHz           | 30                            | 75 | 100 | 100 | 100 | 100 | 100 |
| 433 MHz           | 20                            | 50 | 75  | 100 | 100 | 100 | 100 |
| 868 MHz           | 10                            | 25 | 40  | 60  | 75  | 100 | 100 |
| 915 MHz           | 10                            | 25 | 40  | 50  | 75  | 75  | 100 |

| Bit Rate: 9.6kbps | Transmitter Deviation [± kHz] |    |     |     |     |     |     |
|-------------------|-------------------------------|----|-----|-----|-----|-----|-----|
|                   | 30                            | 60 | 90  | 120 | 150 | 180 | 210 |
| 315 MHz           | 25                            | 70 | 100 | 100 | 100 | 100 | 100 |
| 433 MHz           | 15                            | 50 | 75  | 100 | 100 | 100 | 100 |
| 868 MHz           | 8                             | 25 | 40  | 60  | 75  | 75  | 100 |
| 915 MHz           | 8                             | 25 | 40  | 50  | 70  | 75  | 100 |

| Bit Rate: 38.3kbps | Transmitter Deviation [± kHz] |    |    |     |     |     |     |
|--------------------|-------------------------------|----|----|-----|-----|-----|-----|
|                    | 30                            | 60 | 90 | 120 | 150 | 180 | 210 |
| 315 MHz            | don't use                     | 30 | 75 | 100 | 100 | 100 | 100 |
| 433 MHz            | don't use                     | 20 | 50 | 75  | 100 | 100 | 100 |
| 868 MHz            | don't use                     | 10 | 30 | 40  | 60  | 75  | 100 |
| 915 MHz            | don't use                     | 10 | 25 | 40  | 60  | 75  | 75  |

Whenever a low frequency error is essential for the application, it is possible to “pull” the crystal to the accurate frequency by changing the load capacitor value. The widest pulling range can be achieved if the nominal required load capacitance of the crystal is in the “midrange”, for example 16 pF. The “pull-ability” of the crystal is defined by its motional capacitance and  $C_0$ .

**Note:** There may be other requirements for the TX carrier accuracy with regards to the requirements as defined by standards and/or channel separations.

## RESET MODES

The chip will enter into reset mode if any of the following conditions are met:

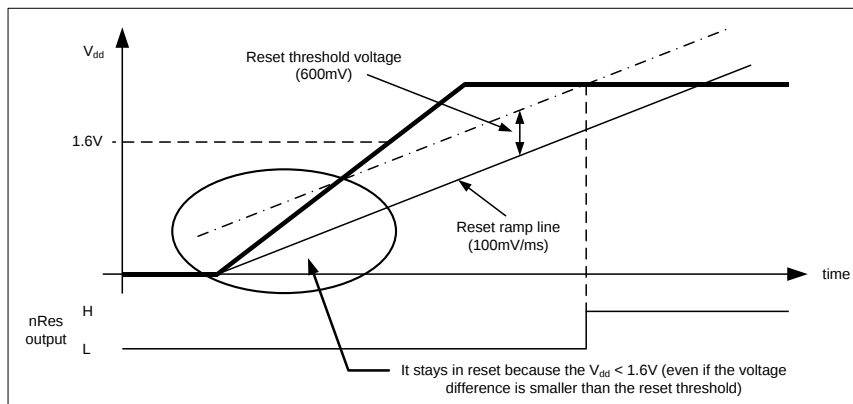
- Power-on reset: During a power up sequence until the  $V_{dd}$  has reached the correct level and stabilized
- Power glitch reset: Transients present on the  $V_{dd}$  line
- Software reset: Special control command received by the chip

### Power-on reset

After power up the supply voltage starts to rise from 0V. The reset block has an internal ramping voltage reference (reset-ramp signal), which is rising at 100mV/ms (typical) rate. The chip remains in reset state while the voltage difference between the actual  $V_{dd}$  and the internal reset-ramp signal is higher than the reset threshold voltage, which is 600 mV (typical). As long as the  $V_{dd}$  voltage is less than 1.6V (typical) the chip stays in reset mode regardless the voltage difference between the  $V_{dd}$  and the internal ramp signal.

The reset event can last up to 150ms supposing that the  $V_{dd}$  reaches 90% its final value within 1ms. During this period the chip does not accept control commands via the serial control interface.

Power-on reset example:



### Power glitch reset

The internal reset block has two basic mode of operation: normal and sensitive reset. The default mode is sensitive, which can be changed by the appropriate control command (see *Related control commands* at the end of this section). In normal mode the power glitch detection circuit is disabled.

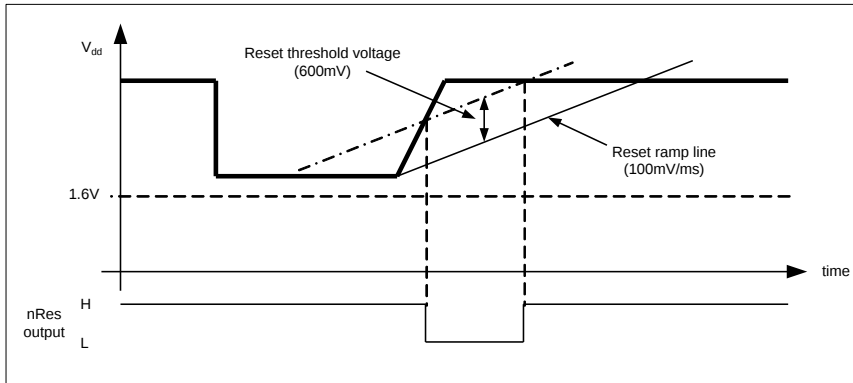
There can be spikes or glitches on the  $V_{dd}$  line if the supply filtering is not satisfactory or the internal resistance of the power supply is too high. In such cases if the sensitive reset is enabled an (unwanted) reset will be generated if the positive going edge of the  $V_{dd}$  has a rising rate greater than 100mV/ms and the voltage difference between the internal ramp signal and the  $V_{dd}$  reaches the reset threshold voltage (600 mV). Typical case when the battery is weak and due to its increased internal resistance a sudden decrease of the current consumption (for example turning off the power amplifier) might lead to an increase in supply voltage. If for some reason the sensitive reset cannot be disabled step-by-step decrease of the current consumption (by turning off the different stages one by one) can help to avoid this problem.

Any negative change in the supply voltage will not cause reset event unless the  $V_{dd}$  level reaches the reset threshold voltage (250mV in normal mode, 1.6V in sensitive reset mode).

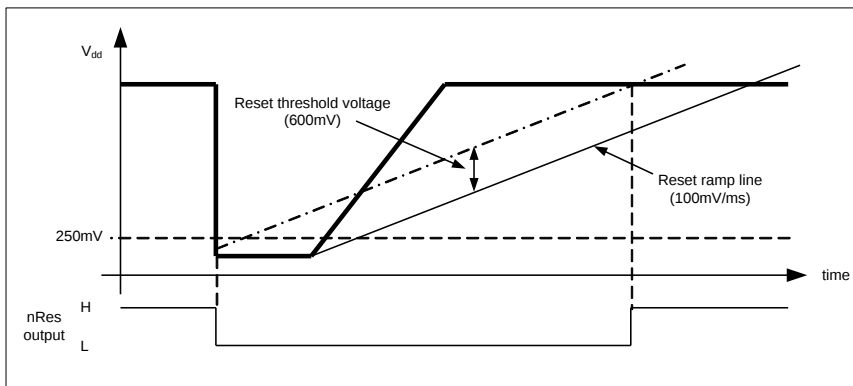
If the sensitive mode is disabled and the power supply turned off the  $V_{dd}$  must drop below 250mV in order to trigger a power-on reset event when the supply voltage is turned back on. If the decoupling capacitors keep their charges for a long time it could happen that no reset will be generated upon power-up because the power glitch detector circuit is disabled.

Note that the reset event reinitializes the internal registers, so the sensitive mode will be enabled again.

Sensitive Reset Enabled, Ripple on  $V_{dd}$ :



Sensitive reset disabled:



### Software reset

Software reset can be issued by sending the appropriate control command (described at the end of the section) to the chip. The result of the command is the same as if power-on reset was occurred.

### $V_{dd}$ line filtering

During the reset event (caused by power-on, fast positive spike on the supply line or software reset command) it is very important to keep the  $V_{dd}$  line as smooth as possible. Noise or periodic disturbing signal superimposed the supply voltage may prevent the part getting out from reset state. To avoid this phenomenon use adequate filtering on the power supply line to keep the level of the disturbing signal below  $10\text{mV}_{p-p}$  in the DC –  $50\text{kHz}$  range for  $200\text{ms}$  from  $V_{dd}$  ramp start.. Typical example when a switch-mode regulator is used to supply the radio, switching noise may be present on the  $V_{dd}$  line. Follow the manufacturer's recommendations how to decrease the ripple of the regulator IC and/or how to shift the switching frequency.

### Related control commands

#### "Low Battery Detector Command"

Setting bit<6> to high will change the reset mode to normal from the default sensitive.

#### "SW Reset Command"

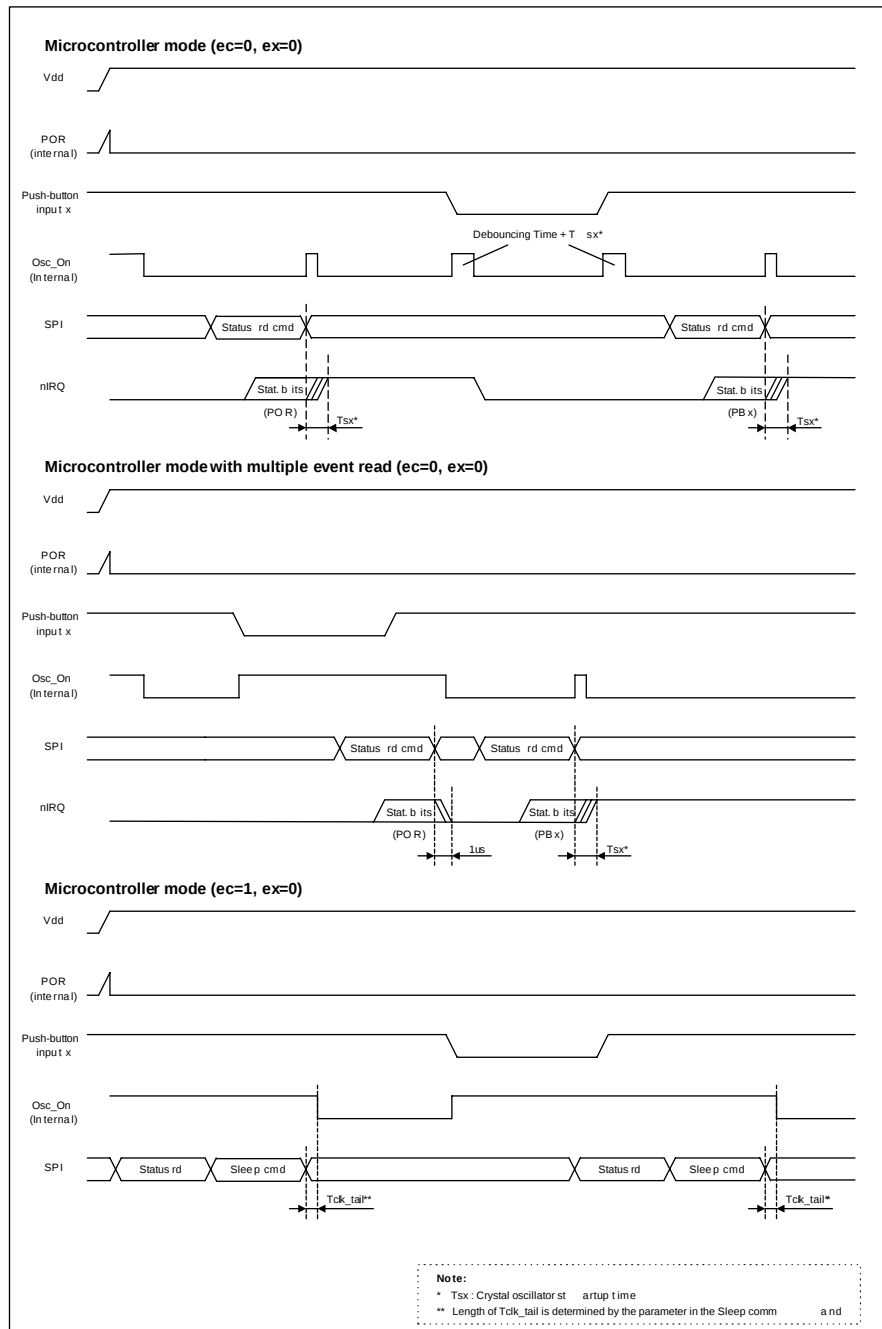
Issuing FF00h command will trigger software reset. See the *Wake-up Timer Command*.

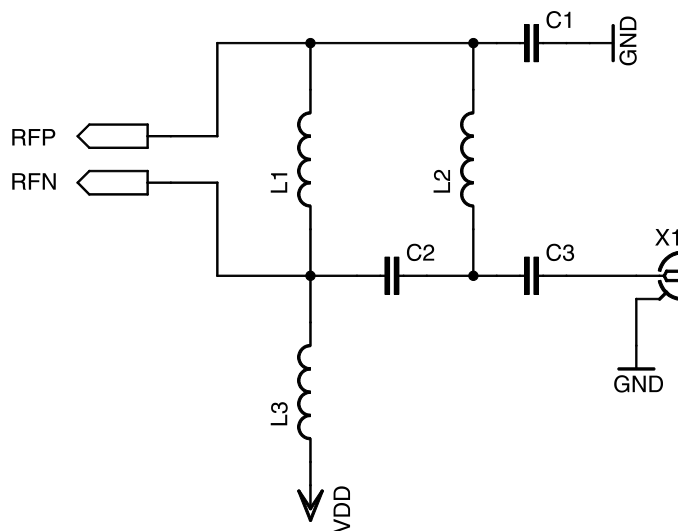
## SIMPLIFIED INTERNAL CONTROL AND TIMING

The internal controller uses the clock generated by the crystal oscillator to sequentially process the various events and to de-bounce the push-button (PB) inputs. If the oscillator is not running, internal logic automatically turns it on temporarily and then off again. Such events are: any wake-up event (POR, PB press, wake-up timer timeout, and low supply voltage detection), PB release and status read request by the microcontroller.

If two wake-up events occur in succession, the crystal oscillator stays on until the next status read (acknowledgment of the first event).

### Simplified Internal Control and Timing Diagrams



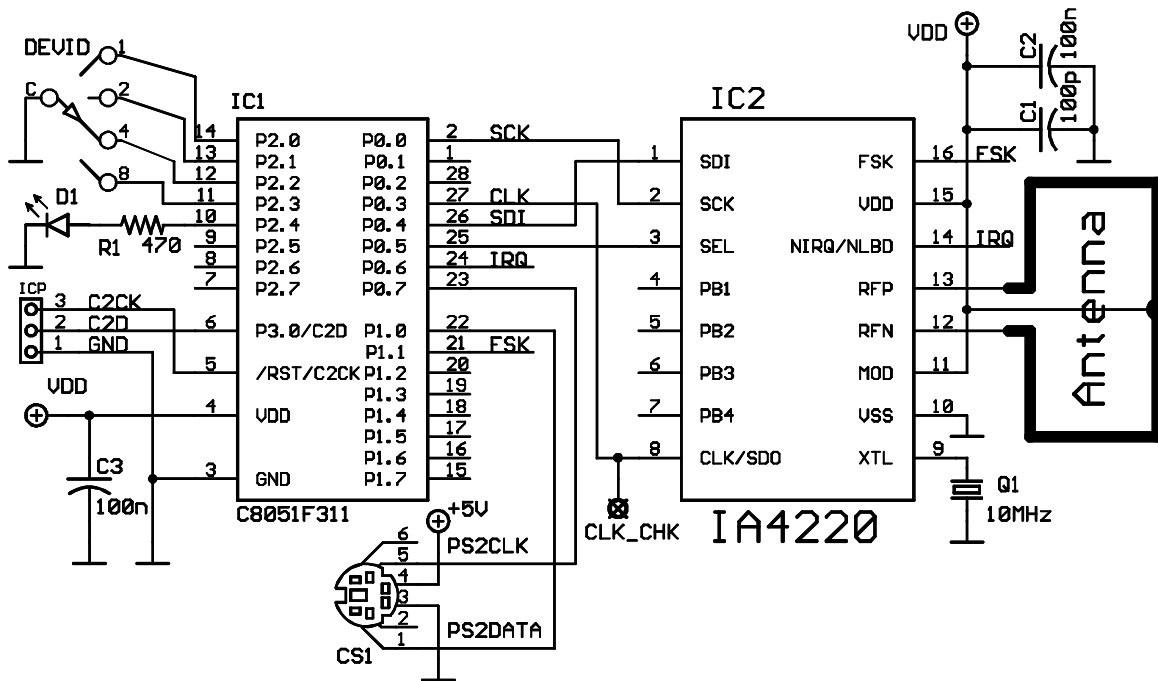
**MATCHING NETWORK FOR A 50 OHM SINGLE ENDED OUTPUT*****Matching Network Schematic***

| Si4020  | L1 [nH] | L2 [nH] | L3 [nH] | C1 [pF] | C2 [pF] | C3 [pF] |
|---------|---------|---------|---------|---------|---------|---------|
| 315 MHz | 72      | 110     | 390     | 3.9     | 2.2     | 56..100 |
| 433 MHz | 43      | 82      | 390     | 2.7     | 1.5     | 56..100 |
| 868 MHz | 10      | 27      | 100     | 1.8     | 1       | 27..56  |
| 915 MHz | 10      | 27      | 100     | 1.8     | 1       | 27..56  |

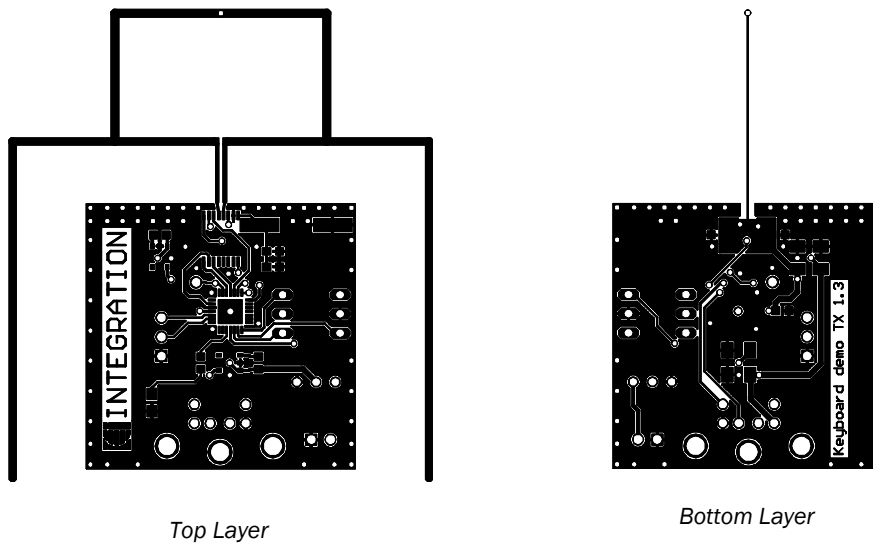
## EXAMPLE APPLICATIONS

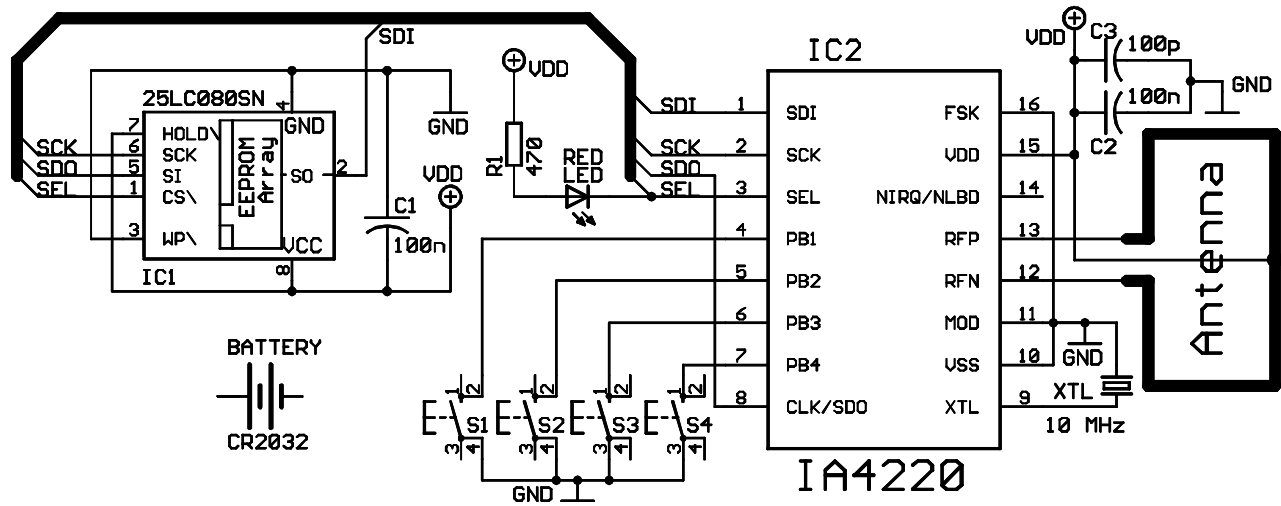
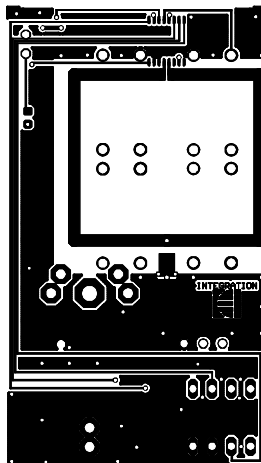
### For Microcontroller Mode

#### Schematic

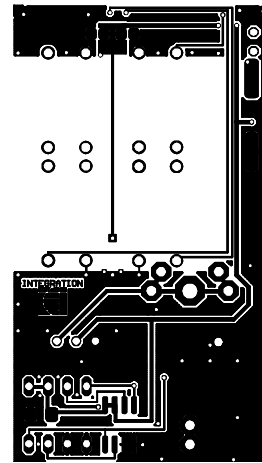


PCB Layout of Keyboard Transmitter Demo Circuit Using Microcontroller Mode (operating in the 915 MHz band)



**For EEPROM Mode****Schematic****PCB Layout of Push-Button Transmitter Demo Circuit Using EEPROM Mode (operating in the 434 MHz band)**

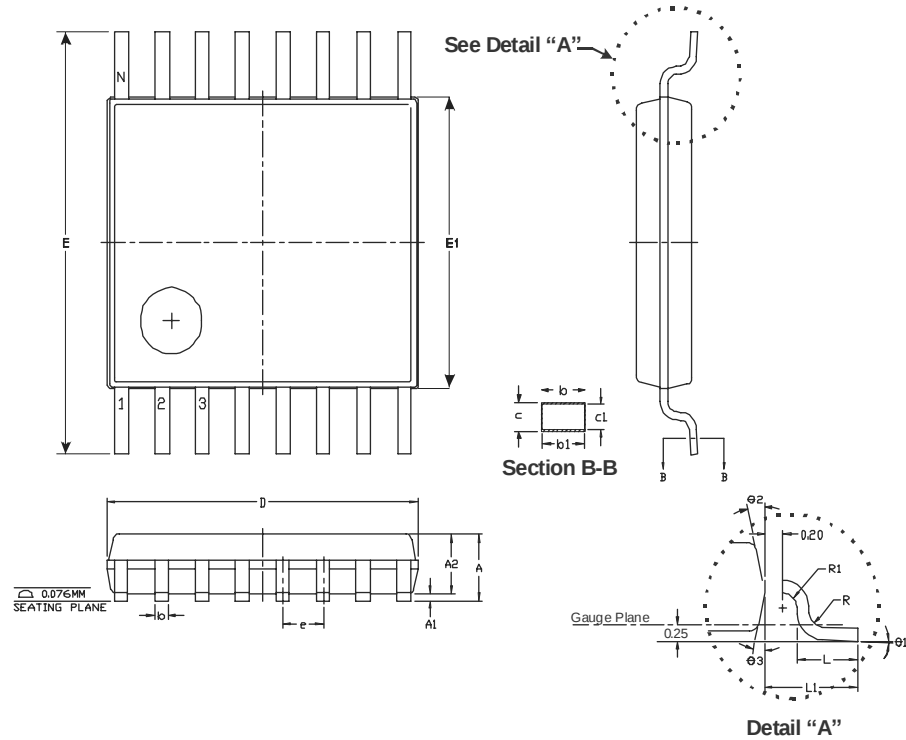
Top Layer



Bottom Layer

## PACKAGE INFORMATION

## 16-pin TSSOP



| Symbol | Dimensions in mm |      |      | Dimensions in Inches |       |       |
|--------|------------------|------|------|----------------------|-------|-------|
|        | Min.             | Nom. | Max. | Min.                 | Nom.  | Max.  |
| A      |                  |      | 1,20 |                      |       | 0,047 |
| A1     | 0,05             |      | 0,15 | 0,002                |       | 0,006 |
| A2     | 0,80             | 0,90 | 1,05 | 0,031                | 0,035 | 0,041 |
| b      | 0,19             |      | 0,30 | 0,007                |       | 0,012 |
| b1     | 0,19             | 0,22 | 0,25 | 0,007                | 0,009 | 0,010 |
| c      | 0,09             |      | 0,20 | 0,004                |       | 0,008 |
| c1     | 0,09             |      | 0,16 | 0,004                |       | 0,006 |
| D      | 4,90             | 5,00 | 5,10 | 0,193                | 0,197 | 0,201 |
| e      | 0.65 BSC.        |      |      | 0.026 BSC.           |       |       |
| E      | 6.40 BSC.        |      |      | 0.252 BSC.           |       |       |
| E1     | 4,30             | 4,40 | 4,50 | 0,169                | 0,173 | 0,177 |
| L      | 0,50             | 0,60 | 0,75 | 0,020                | 0,024 | 0,030 |
| L1     | 1.00 REF.        |      |      | 0.39 REF.            |       |       |
| R      | 0,09             |      |      | 0,004                |       |       |
| R1     | 0,09             |      |      | 0,004                |       |       |
| θ1     | 0                |      | 8    | 0                    |       | 8     |
| θ2     | 12 REF.          |      |      | 12 REF.              |       |       |
| θ3     | 12 REF.          |      |      | 12 REF.              |       |       |

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## RELATED PRODUCTS AND DOCUMENTS

### Si4020 Universal ISM Band FSK Transmitter

| DESCRIPTION         | ORDERING NUMBER       |
|---------------------|-----------------------|
| Si4020 16-pin TSSOP | Si4020-IC CC16 Rev I1 |
| die                 | see Silicon Labs      |

### Demo Boards and Development Kits

| DESCRIPTION                           | ORDERING NUMBER |
|---------------------------------------|-----------------|
| Development Kit                       | IA ISM – DK     |
| Remote Temperature Monitoring Station | IA ISM – DATD   |

### Related Resources

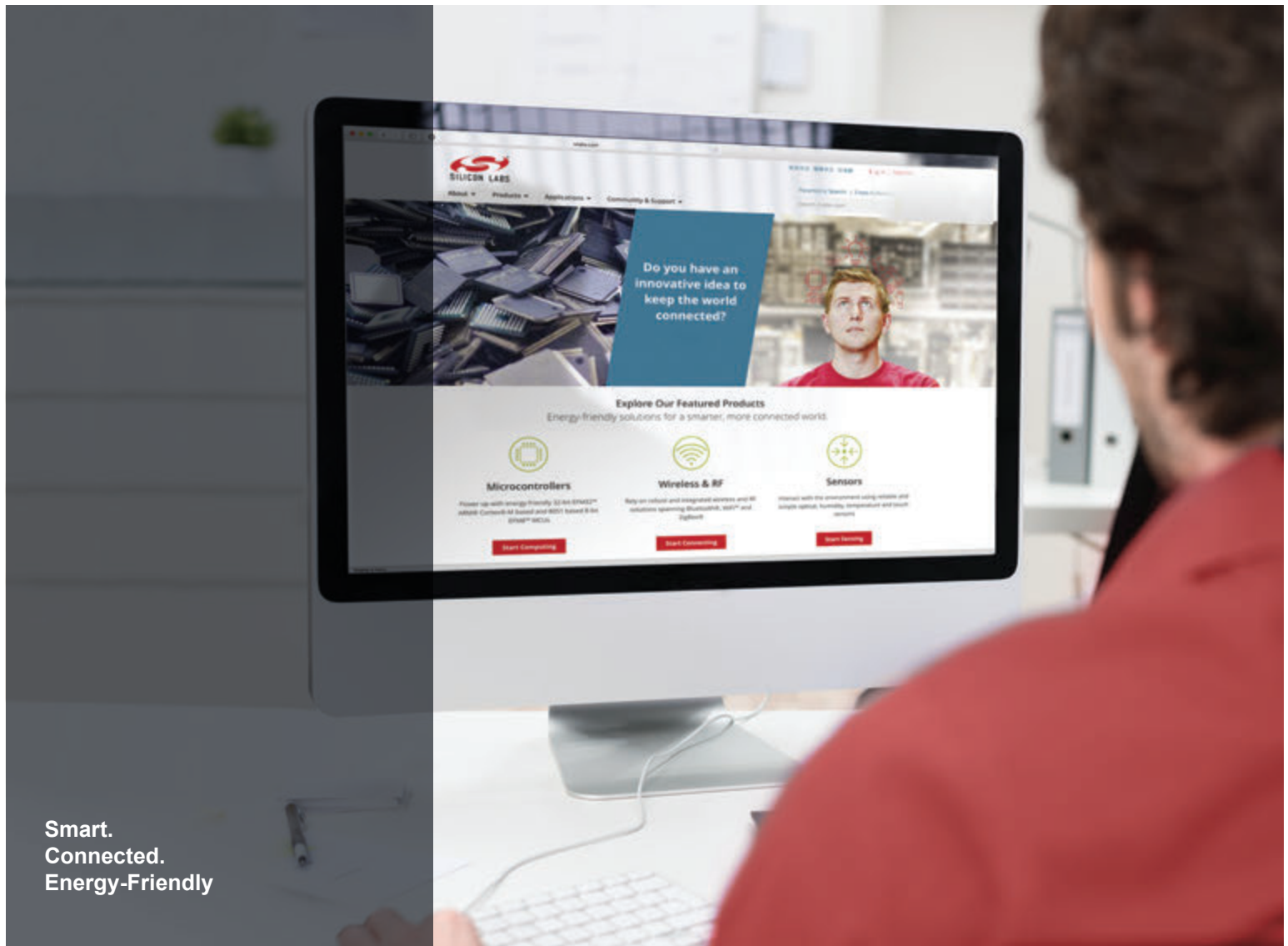
| DESCRIPTION                            | ORDERING NUMBER                                                                            |
|----------------------------------------|--------------------------------------------------------------------------------------------|
| Antenna Selection Guide                | IA ISM – AN1                                                                               |
| Antenna Development Guide              | IA ISM – AN2                                                                               |
| IA4320 Universal ISM Band FSK Receiver | See <a href="http://www.silabs.com/integration">www.silabs.com/integration</a> for details |

**Note:** Volume orders must include chip revision to be accepted.

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Toll Free: 877.444.3032  
[www.silabs.com/integration](http://www.silabs.com/integration)  
[wireless@silabs.com](mailto:wireless@silabs.com)

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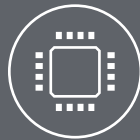
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